مسمهد «مسدد

Substitute for Form 1449A/PTO (Modified) (use as many sheets as necessary)					Attorney Docket No.: 42390.P11005	Application Number: 09/814,424			
MAR 0 5 2003 2					First Named Inventor:	Francisco A. Leo	Francisco A. Leon et al.		
					Filing Date:	March 21, 2001			
U.S. PATENT DOCUMENTS									
Exam. Initial*	Cite No. ¹	U.S. Patent Number Code ²	Document Kind (If known)	Na	me of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
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M		0 462 599	A2	APPLIED MATERIALS, INC.	12/27/1991		
4		07140341		HITACHI LTD	06/02/1995		
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	Examiner Signature	Mit In	Date Considered	8/1/2000
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¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard S.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

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C	MAR 0 5	3003 E	First Named Inventor: Francisco A. Leon et al. Filing Date: March 21, 2001				
OTHER ART - NO PATENT LITERATURE DOCUMENTS							
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ζŊ		SHANI, Y., et al., "Buried Rib Passive Waveguide Y Junctions With Sharp Vertex On InP", IEEE Photonics Technology Letters, Vol. 3, No. 3 (March 1991) pp. 210-212					
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